

# SIHS36N50D-E3

### SIHS36N50D-E3 Information





**Request a Quote** 

For Reference Only

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# SIHS36N50D-E3 Specifications

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Manufacturer Part Number	SIHS36N50D-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	36A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	125nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3233pF @ 100V
Vgs (Max)	$\pm 30 V$
FET Feature	-
Power Dissipation (Max)	446W (Tc)
Rds On (Max) @ Id, Vgs	130 mOhm @ 18A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	SUPER-247 (TO-274AA)
Package / Case	TO-247-3
	Report errors?

E-mail: salesdept@heisener.com

#### SIHS36N50D-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE BUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SIHS36N50D-E3 Payment Methods



## SIHS36N50D-E3 Shipping Methods



If you have any question about SIHS36N50D-E3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com